



**Solid State Devices, Inc.**

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**SFT85707GW**

**Dual Microminiature Package  
 NPN & PNP Pair  
 Small Signal / RF Transistor**

**DESIGNER'S DATA SHEET**

**Part Number / Ordering Information**<sup>1/</sup>

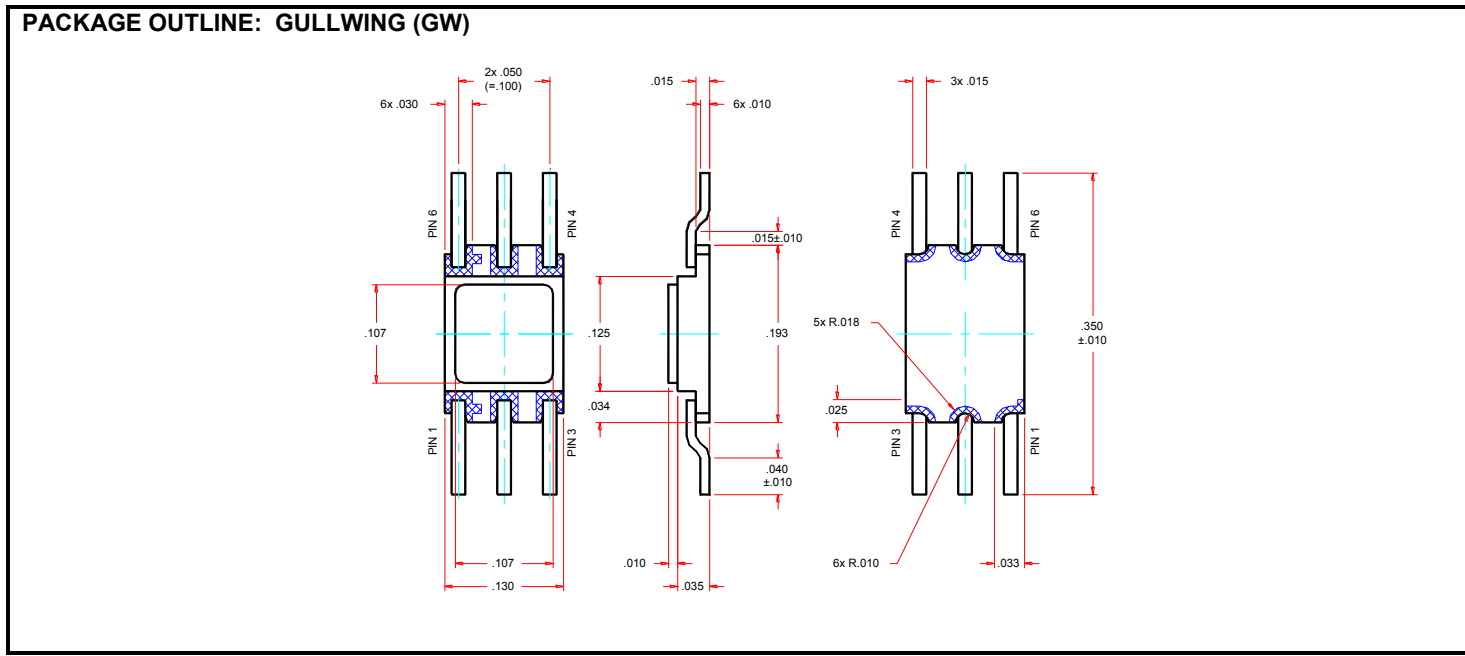
SFT85707 \_ \_

Screening<sup>2/</sup> \_ \_ = Not Screened  
 TX = TX Level  
 TXV = TXV Level  
 S = S Level

Package<sup>3/</sup> GW = GULLWING

- Features:**
- High Speed, Saturated Switching, and Driver Applications
  - Low Power IF and RF Amplifier Applications in the UHF Range
  - TX, TXV, S-Level Screening Available<sup>2/</sup>

Maximum Ratings		Symbol	2N2857 NPN	2N2907 PNP	Units
Collector – Emitter Voltage		V <sub>CEO</sub>	15	60	Volts
Collector – Base Voltage		V <sub>CB0</sub>	30	60	Volts
Emitter – Base Voltage		V <sub>EBO</sub>	3.0	5.0	Volts
Collector Current		I <sub>C</sub>	40	600	mA
Power Dissipation Per Device	T <sub>A</sub> = 25°C	P <sub>D</sub> <sup>5/</sup>	200	500	mW
Total Power Dissipation	T <sub>A</sub> = 25°C	P <sub>D</sub> <sup>5/</sup>	660		mW
Maximum Thermal Resistance	(Junction to Ambient)	R <sub>0JA</sub> <sup>5/</sup>	880	350	°C/W
Operating & Storage Temperature		T <sub>J</sub> & T <sub>STG</sub>	-65 to +200	-65 to +200	°C



**NOTE:** All specifications are subject to change without notification. SCDC's for these devices should be reviewed by SSDI prior to release.

**DATA SHEET #: TR0079D**

**DOC**



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Electrical Characteristics <sup>4/</sup>	Symbol	NPN Bias	Limit	PNP Bias	Limit
Collector – Emitter Blocking Voltage *	$BV_{CEO}$	$I_C = 3 \text{ mA}$	15 V min	$I_C = 10 \text{ mA}$	-60 V min
Collector – Base Leakage Current	$I_{CBO1}$	$V_{CB} = 30 \text{ V}$	1 uA max	$V_{CB} = 60 \text{ V}$	-10 uA max
Emitter – Base Leakage Current	$I_{EBO}$	$V_{BE} = 3 \text{ V}$	10 uA max	$V_{BE} = 5 \text{ V}$ $V_{BE} = 4 \text{ V}$	-10 uA max -50 nA max
Collector Cutoff Current	$I_{CBO2}$	$V_{CB} = 15 \text{ V}$ $V_{CB} = 15 \text{ V}, T_A = 150^\circ\text{C}$	10 nA max 1 uA max	$V_{CB} = -50 \text{ V}, T_A = 25^\circ\text{C}$ $V_{CB} = -50 \text{ V}, T_A = 150^\circ\text{C}$	-10 nA max -10 uA max
Emitter Cutoff Current	$I_{CES}$	$V_{CE} = 16 \text{ V}, V_{BE} = 0 \text{ V}$	100 nA	$V_{CE} = -50 \text{ V}, V_{BE} = 0 \text{ V}$	50 nA
DC Current Forward Transfer Ratio *	$h_{FE}$	$I_C = 3 \text{ mA}, V_{CE} = 1 \text{ V}$	30 - 150	—	—
DC Current Forward Transfer Ratio *	$h_{FE}$	—	—	$I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ $I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$ $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}$ $I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}$ $I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}$	75 min 100 - 450 100 min 100 - 300 50 min
Small Signal Current Gain * (f = 1 kHz)	$h_{fe}$	$I_C = 2 \text{ mA}, V_{CE} = 6 \text{ V}$	20 - 220	$I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$	100 min
Collector-Emitter Saturation Voltage *	$V_{CE(SAT)}$	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$	0.4 V max	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$	-0.4 V max -1.6 V max
Base-Emitter Saturation Voltage *	$V_{BE(SAT)}$	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$	1.0 V max	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$	-1.3 V max -2.6 V max
Small-Signal Power Gain	$G_{pe}$	$I_C = 1.5 \text{ mA}, V_{CE} = 6 \text{ V},$ $f = 450 \text{ MHz}$ <sup>6/</sup>	12.5 – 21 dB	—	—
Noise Figure	NF	$I_C = 1.5 \text{ mA}, V_{CE} = 6 \text{ V},$ $f = 450 \text{ MHz}$ <sup>6/</sup>	4.5 dB max	—	—
Current Gain – Bandwidth Product	$f_T$	$V_{CE} = 6 \text{ V}, I_C = 5 \text{ mA},$ $f = 100 \text{ MHz}$	1.0 GHz min	$V_{CE} = -20 \text{ V}, I_C = 20 \text{ mA},$ $f = 100 \text{ MHz}$	200 MHz min
Collector Base Time Constant	$R_b C_c$	$V_{CB} = 6 \text{ V}, I_E = 2 \text{ mA},$ $f = 31.9 \text{ MHz}$ <sup>6/</sup>	4 - 15 ps	—	—
Output Capacitance	$C_{ob/cb}$	$V_{CB} = 10 \text{ V}, I_E = 0 \text{ A},$ $f = 0.1 \text{ to } 1 \text{ MHz}$	1.0 pF max	$V_{CB} = -10 \text{ V}, I_E = 0 \text{ A},$ $f = 1.0 \text{ MHz}$	8 pF max
Input Capacitance	$C_{ib}$	—	—	$V_{BE} = -2.0 \text{ V}, I_C = 0 \text{ A},$ $f = 1.0 \text{ MHz}$	30 pF max
Delay Time	$t_{(on)}$	$t_d$	—	$V_{CC} = -30 \text{ V}, I_C = 150 \text{ mA},$ $I_{B1} = I_{B2} = 15 \text{ mA}$	45 ns max
Rise Time			$t_r$		
Storage Time	$t_{(off)}$	$t_s$	—	$V_{CC} = -6 \text{ V}, I_C = 150 \text{ mA},$ $I_{B1} = I_{B2} = 15 \text{ mA}$	300 ns max
Fall Time			$t_f$		

<b>NOTES:</b> * Pulse Test: Pulse Width = 300µsec, Duty Cycle = 2% <sup>1/</sup> For Ordering Information, Price, and Availability Contact Factory. <sup>2/</sup> Screening based on MIL-PRF-19500. Screening flows available on request.	<sup>3/</sup> For Package Outlines Contact Factory.
	<sup>4/</sup> Unless Otherwise Specified, All Electrical Characteristics @25°C
	<sup>5/</sup> Mounted on F__ PCB
	<sup>6/</sup> parameter guaranteed by design

**Available Part Numbers:**  
**SFT85707GW**

PIN ASSIGNMENT						
Package	Pin 1	Pin 2	Pin 3	Pin 4	Pin 5	Pin 6
Gullwing	Collector	Base	Emitter	Collector	Base	Emitter
	PNP	PNP	PNP	NPN	NPN	NPN